

PHASE CONTROL THYRISTORS

Hockey Puk Version

Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AB (A-PUK)
- Extended temperature range

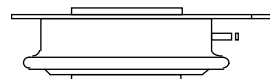
Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

Major Ratings and Characteristics

Parameters	ST280CH..C	Units	
$I_{T(AV)}$	500	A	
@ T_{hs}	80	°C	
$I_{T(RMS)}$	1130	A	
@ T_{hs}	25	°C	
I_{TSM}	@ 50Hz	7200	A
	@ 60Hz	7500	A
I^2t	@ 50Hz	260	KA ² s
	@ 60Hz	230	KA ² s
V_{DRM}/V_{RRM}	400 to 600	V	
t_q typical	100	μs	
T_J	- 40 to 150	°C	

500A



case style TO-200AB (A-PUK)

ST280CH..C Series

Bulletin I25160 rev. C 02/00

International
 Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{DRM}/V_{RRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_J = T_J$ max mA
ST280CH..C	04	400	500	75
	06	600	700	

On-state Conduction

Parameter	ST280CH..C	Units	Conditions	
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	500 (185)	A	180° conduction, half sine wave	
	80 (110)	°C	double side (single side) cooled	
$I_{T(RMS)}$ Max. RMS on-state current	1130	A	DC @ 25°C heatsink temperature double side cooled	
I_{TSM} Max. peak, one-cycle non-repetitive surge current	7200		t = 10ms	No voltage reappplied
	7500		t = 8.3ms	reappplied
	6000		t = 10ms	100% V_{RRM}
	6300	t = 8.3ms	reappplied	
I^2t Maximum I^2t for fusing	260	KA ² s	t = 10ms	No voltage reappplied
	235		t = 8.3ms	reappplied
	180		t = 10ms	100% V_{RRM}
	165		t = 8.3ms	reappplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	2600	KA ² √s	t = 0.1 to 10ms, no voltage reappplied	
$V_{T(TO)1}$ Low level value of threshold voltage	0.84	V	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ max.	
$V_{T(TO)2}$ High level value of threshold voltage	0.88		$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ max.	
r_{t1} Low level value of on-state slope resistance	0.50	mΩ	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ max.	
r_{t2} High level value of on-state slope resistance	0.47		$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ max.	
V_{TM} Max. on-state voltage	1.35	V	$I_{pk} = 1000A$, $T_J = T_J$ max, $t_p = 10ms$ sine pulse	
I_H Maximum holding current	600	mA	$T_J = 25^\circ C$, anode supply 12V resistive load	
I_L Max (typical) latching current	1000 (300)			

Switching

Parameter	ST280CH..C	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/μs	Gate drive 20V, 20Ω, $t_r \leq 1\mu s$ $T_J = T_J$ max, anode voltage $\leq 80\% V_{DRM}$
t_d Typical delay time	1.0	μs	Gate current 1A, $di_g/dt = 1A/\mu s$ $V_d = 0.67\% V_{DRM}$, $T_J = 25^\circ C$
t_q Typical turn-off time	100		$I_{TM} = 300A$, $T_J = T_J$ max, $di/dt = 20A/\mu s$, $V_R = 50V$ $dv/dt = 20V/\mu s$, Gate 0V 100Ω, $t_p = 500\mu s$

Blocking

Parameter	ST280CH..C	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ μ s	$T_J = T_J$ max. linear to 80% rated V_{DRM}
I_{DRM} I_{RRM} Max. peak reverse and off-state leakage current	75	mA	$T_J = T_J$ max, rated V_{DRM}/V_{RRM} applied

Triggering

Parameter	ST280CH..C	Units	Conditions
P_{GM} Maximum peak gate power	10.0	W	$T_J = T_J$ max, $t_p \leq 5$ ms
$P_{G(AV)}$ Maximum average gate power	2.0		$T_J = T_J$ max, $f = 50$ Hz, $d\% = 50$
I_{GM} Max. peak positive gate current	3.0	A	$T_J = T_J$ max, $t_p \leq 5$ ms
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J$ max, $t_p \leq 5$ ms
$-V_{GM}$ Maximum peak negative gate voltage	5.0		
I_{GT} DC gate current required to trigger	TYP.	MAX.	$T_J = -40^\circ\text{C}$ $T_J = 25^\circ\text{C}$ $T_J = 150^\circ\text{C}$ Max. required gate trigger/ current/ voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
	180	-	
	90	150	
V_{GT} DC gate voltage required to trigger	2.9	-	$T_J = -40^\circ\text{C}$ $T_J = 25^\circ\text{C}$ $T_J = 150^\circ\text{C}$
	1.8	3.0	
	1.0	-	
I_{GD} DC gate current not to trigger	10	mA	$T_J = T_J$ max Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V_{DRM} anode-to-cathode applied
V_{GD} DC gate voltage not to trigger	0.30	V	

Thermal and Mechanical Specification

Parameter	ST280CH..C	Units	Conditions
T_J Max. operating temperature range	-40 to 150	$^\circ\text{C}$	
T_{stg} Max. storage temperature range	-40 to 150		
R_{thJ-hs} Max. thermal resistance, junction to heatsink	0.17	K/W	DC operation single side cooled
	0.08		DC operation double side cooled
R_{thC-hs} Max. thermal resistance, case to heatsink	0.033	K/W	DC operation single side cooled
	0.017		DC operation double side cooled
F Mounting force, $\pm 10\%$	4900	N	
	(500)	(Kg)	
wt Approximate weight	50	g	
Case style	TO - 200AB (A-PUK)		See Outline Table

Outline Table

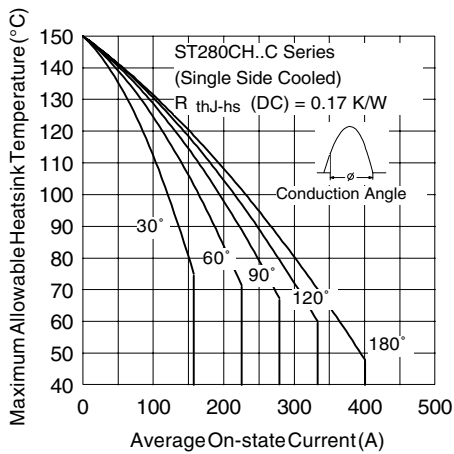
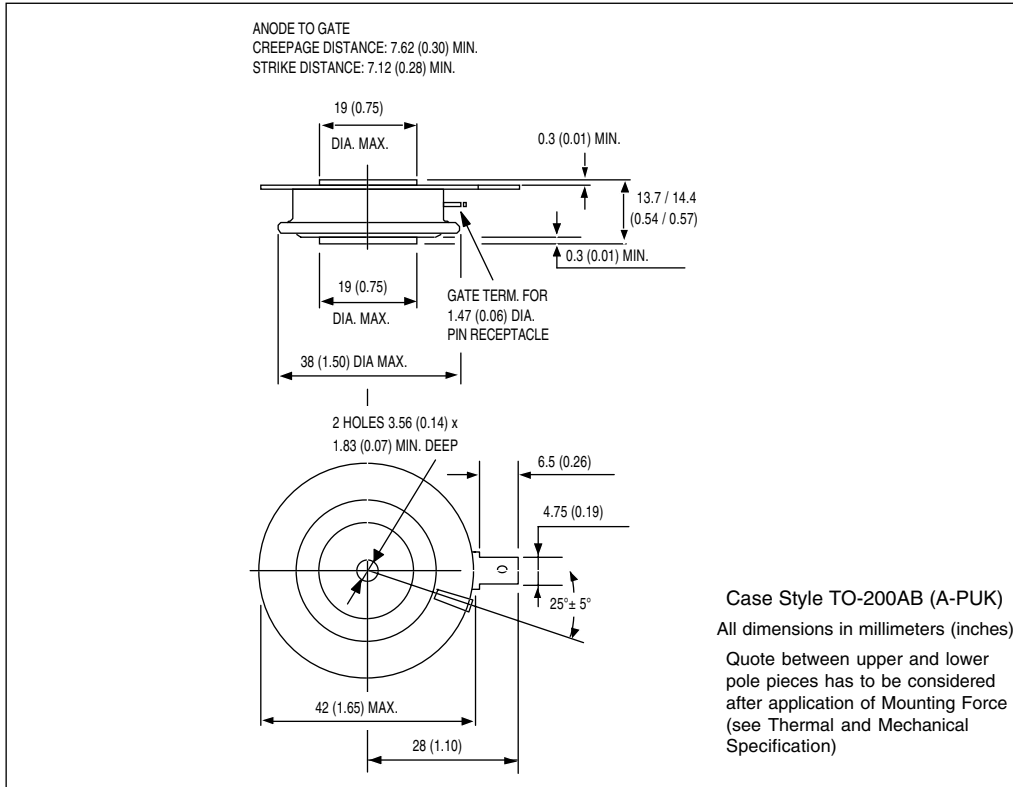


Fig. 1 - Current Ratings Characteristics

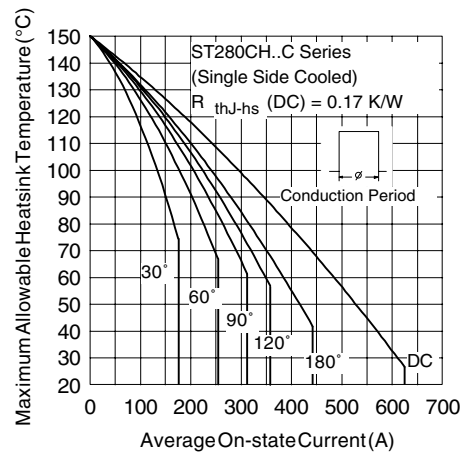


Fig. 2 - Current Ratings Characteristics

ST280C..H Series

Bulletin I25160 rev. C 02/00

International
IOR Rectifier

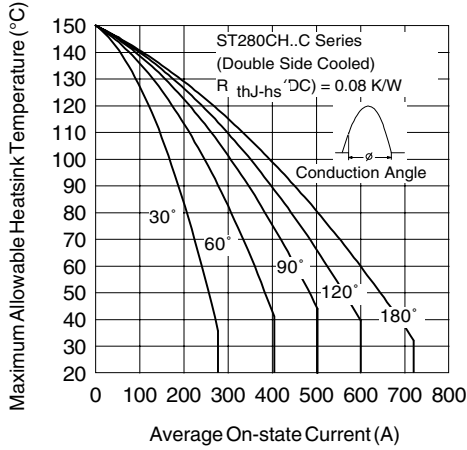


Fig. 3 - Current Ratings Characteristics

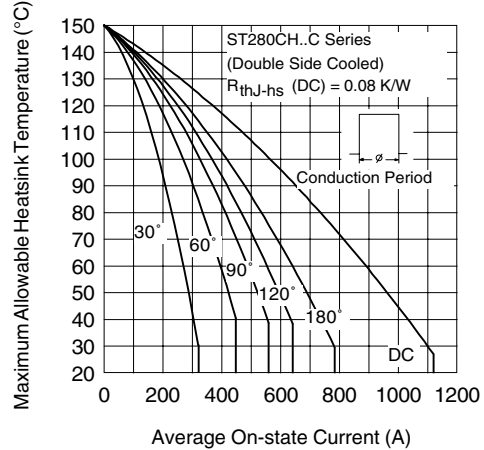


Fig. 4 - Current Ratings Characteristics

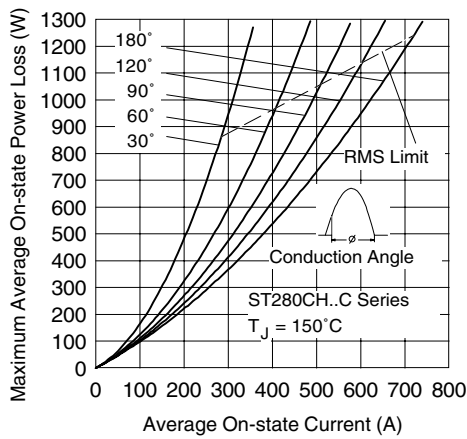


Fig. 5 - On-state Power Loss Characteristics

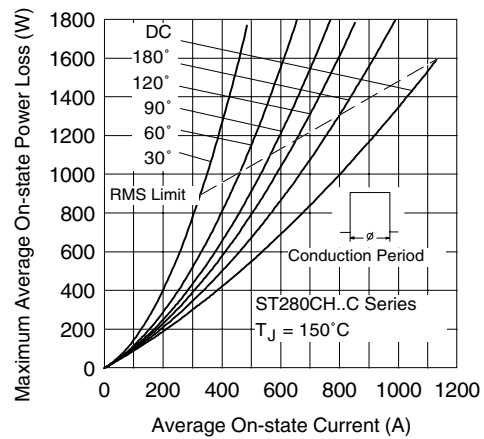


Fig. 6 - On-state Power Loss Characteristics

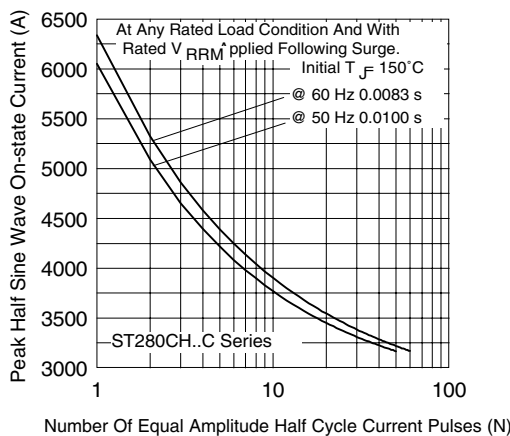


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

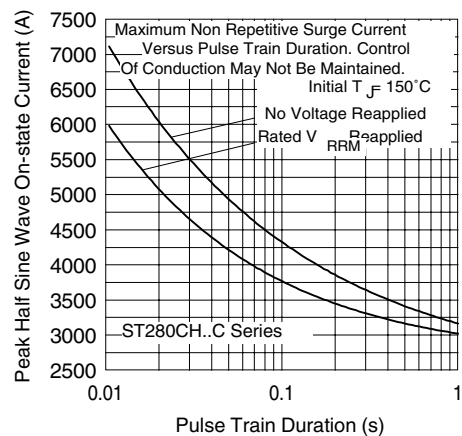


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

Instantaneous On-state Current (A)

Instantaneous On-state Voltage (V)
Fig. 9 - On-state Voltage Drop Characteristics

Transient Thermal Impedance Z_{th-JHS} (K/W)

Square Wave Pulse Duration (s)
Fig. 10 - Thermal Impedance Z_{th-JHS} Characteristics

Instantaneous Gate Voltage (V)

Instantaneous Gate Current (A)
Fig. 11 - Gate Characteristics



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